

YJ Planar Fast Recovery Diode Die Specification

200V 8A, Fast recovery diode die based on silicon planar process
Part No.: FRD08A200AS-290A

Main Products Characterstics

Maximum Ratings

Static Electrical Characteristics (Ta = 25°C)

Device Schematics and Outline Drawing

- Die Thickness
- Die Size *
- Top Metal Pad
- Active Area
- Top Metal
- Back Metal
- Note: 1 *: Cutting street width is around 40um

Important Notice

Specification apply to die only. Actual performance may degrade when assembled.
does not guarantee device performance after assembly.

Recommended Storage Environment:
Store in original container, in dessicated nitrogen, with no contamination.